

General Description

The MAX4624/MAX4625 are low-on-resistance, lowvoltage single-pole/double-throw (SPDT) analog switches that operate from a single +1.8V to +5.5V supply. The MAX4624 has break-before-make switching; the MAX4625 has make-before-break switching. These devices also have fast switching speeds (ton = 50ns max, tOFF = 50ns max).

When powered from a +5V supply, the MAX4624/ MAX4625 offer 1Ω max on-resistance (RON), with 0.12Ω max RON matching and flatness. The digital logic inputs are TTL compatible when using a single +5V supply. These switches also feature overcurrent protection to prevent damage from short circuits and excessive loads.

The MAX4624/MAX4625 are pin compatible with the MAX4544 and are available in space-saving standard 6-pin SOT23 packages, as well as the 1.0mm high Thin SOT package.

Applications

Power Routing

Battery-Operated Equipment

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

PCMCIA Cards

Cellular Phones

Modems

Hard Drives

Features

♦ Low Ron

1 Ω max (+5V Supply) 2Ω max (+3V Supply)

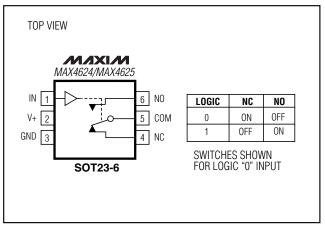
- ♦ 0.12Ω max Ron Flatness (+5V Supply)
- **♦** Overcurrent Protection
- ♦ +1.8V to +5.5V Single-Supply Operation
- ♦ Available in SOT23 Packages
- ♦ Fast Switching: toN = 50ns max, toFF = 50ns max
- ◆ TTL-Logic Compatible (+5V Supply)
- ♦ Pin Compatible with MAX4544
- ♦ Guaranteed Break-Before-Make (MAX4624)
- ♦ Guaranteed Make-Before-Break (MAX4625)

Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	TOP MARK
MAX4624EUT-T	-40°C to +85°C	6 SOT23-6	AADL
MAX4624EZT-T	-40°C to +85°C	6 SOT23-6*	AAAE
MAX4625EUT-T	-40°C to +85°C	6 SOT23-6	AADM
MAX4625EZT-T	-40°C to +85°C	6 SOT23-6*	AAAF

^{*}Thin SOT (1.0mm height) package. Recommended for new designs.

Pin Configuration/ Functional Diagram/Truth Table



ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
V+, IN	0.3V to +6V
COM, NC, NO (Note 1)	0.3V to $(V + + 0.3V)$
Continuous Current NO, NC to COM	±200mA
Peak Current NO, NC to COM	
(pulsed at 1ms, 10% duty cycle max)	±400mA

Continuous Power Dissipation	
6-Pin SOT23 (derate 7.1mW/°C above +	70°C)571mW
6-Pin Thin SOT23 (derate 6.25mW/°C ab	ove +70°C)500mW
Operating Temperature Range	
MAX462_E_T	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C

Note 1: Signals on NC, NO, and COM exceeding V+ or GND are clamped by internal diodes.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V+ = +5V \pm 10\%, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	Ron	$V+ = 4.5V$, V_{NO} or	T _A = +25°C		0.65	1	Ω
On Hoolotanoo	11011	$V_{NC} = 3.5V, I_{COM} = 100mA$	$T_A = T_{MIN}$ to T_{MAX}			1.2	32
On-Resistance Match Between	ΔRON	$V+ = 4.5V$, $I_{COM} = 100mA$,	T _A = +25°C		0.06	0.12	Ω
Channels (Note 4)	Δi (O)(V _{NO} or V _{NC} = 3.5V	$T_A = T_{MIN}$ to T_{MAX}			0.15	32
On-Resistance Flatness	RFLAT(ON)	$V+ = 4.5V; I_{COM} = 100mA;$	T _A = +25°C		0.08	0.12	Ω
(Note 5)	TIFLAT(ON)	V_{NO} or $V_{NC} = 0$, 1V, 2V	$T_A = T_{MIN}$ to T_{MAX}			0.15	_ \2
NO or NC Off-Leakage	INO(OFF),	$V + = 5.5V$; $V_{COM} = 1V$, $4.5V$;	T _A = +25°C	-2	0.01	2	nA
Current	INC(OFF)	V_{NO} or $V_{NC} = 4.5V$, $1V$	$T_A = T_{MIN}$ to T_{MAX}	-20		20	
COM On-Leakage	1	1	T _A = +25°C	-4	0.3	4	nA
Current	ICOM(ON)	V_{NO} or $V_{NC} = 1V$, 4.5V, or floating	$T_A = T_{MIN}$ to T_{MAX}	-40		40	
Overcurrent-Protection Current Threshold		TA = +25°C			1.2		А
DYNAMIC	1						•
Turn-On Time	tou	Mus or Mus 2M Figure 2	T _A = +25°C		40	50	20
Turn-On Time	ton	V_{NO} or $V_{NC} = 3V$, Figure 2	T _A = T _{MIN} to T _{MAX}			60	ns
Turn-Off Time	. ,	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	T _A = +25°C		40	50	ns
rum-Oii Time	tOFF	V_{NO} or $V_{NC} = 3V$, Figure 2	T _A = T _{MIN} to T _{MAX}			60	
Break-Before-Make Delay	+	MAY4604 only Figure 25	T _A = +25°C	1	20		20
(Note 6)	tBBM	MAX4624 only, Figure 3a	T _A = T _{MIN} to T _{MAX}	1			ns
Make-Before-Break Delay	+++00	MAYAGOE only Figure Oh	T _A = +25°C	1	6		20
(Note 6)	tmbb	MAX4625 only, Figure 3b	TA = TMIN to TMAX	1			ns

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V+ = +5V \pm 10\%, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Charge Injection	Q	$C_L = 1.0$ nF, $V_{GEN} = 0$, $R_{GEN} = 0$, $T_A = +25$ °C, Figure 4		65		рС
Off-Isolation (Note 7)	OIRR	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, $T_A = +25$ °C, Figure 5		-57		dB
Crosstalk (Note 8)		$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, $T_A = +25$ °C, Figure 5		-57		dB
NC or NO Off-Capacitance	Coff	f = 1MHz, T _A = +25°C, Figure 6		32		рF
COM On-Capacitance	C _{COM} (ON)	f = 1MHz, T _A = +25°C, Figure 6		100		рF
LOGIC INPUT						
Input Voltage Low	VINL				0.8	V
Input Voltage High	VINH		2.4			V
Logic Input Current	I _{IN}		-1		1	μΑ
SUPPLY	•		•			
Power-Supply Range	V+		1.8		5.5	V
Positive Supply Current	l+	V+ = 5.5V, V _{IN} = 0 or V+			10	μΑ

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+ = +2.7V \text{ to } +3.6V, \text{GND} = 0, \text{V}_{\text{INH}} = 2.0V, \text{V}_{\text{INL}} = 0.6V, \text{T}_{\text{A}} = \text{T}_{\text{MIN}} \text{ to T}_{\text{MAX}}, \text{ unless otherwise noted.})$ (Notes 2, 3)

PARAMETER	SYMBOL	CONE	DITIONS	MIN	TYP	MAX	UNITS
ANALOG SWITCH				'			
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	Davi	V+ = 2.7V,	T _A = +25°C		1.2	2.0	Ω
On-nesistance	Ron	V_{NO} or $V_{NC} = 1.5V$, $I_{COM} = 100mA$	$T_A = T_{MIN}$ to T_{MAX}			2.5	
On-Resistance Flatness (Note 6)	R _{FLAT} (ON)	$V+ = 2.7V$; $I_{COM} = 100$ mA; V_{NO} or $V_{NC} = 0$, 0.75V, 1.5V; $T_{A} = +25$ °C			0.25		Ω
DYNAMIC							1
Turn-On Time	ton	V _{NO} or V _{NC} = 1.5V,	T _A = +25°C		65	80	- ns
Turr-On time	ton	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			100] 115
Turn-Off Time	+055	V_{NO} or $V_{NC} = 1.5V$,	T _A = +25°C		62	80	- ns
Turr-On Time	toff	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			100] 115
Break-Before-Make Time Delay (Note 4)	tBBM	MAX4624 only, Figure 3a		1	40		ns
Make-Before-Break Time Delay (Note 4)	tMBB	MAX4625 only, Figure 3b		1	8		ns
Charge Injection	Q	C_L = 1.0nF, Figure 4, V_{GEN} = 0, RGEN = 0, TA = +25°C			40		рС

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

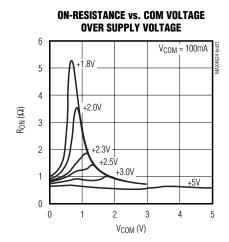
 $(V+ = +2.7V \text{ to } +3.6V, \text{GND} = 0, V_{\text{INH}} = 2.0V, V_{\text{INL}} = 0.6V, T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.})$ (Notes 2, 3)

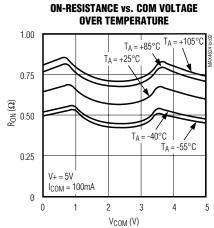
•			, ,			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LOGIC INPUT						
Input Voltage Low	VINL				0.6	V
Input Voltage High	VINH		2.0			V
Logic Input Current	I _{IN}		-1		1	μΑ
SUPPLY			·			•
Positive Supply Current	I+	$V+ = 3.6V, V_{IN} = 0 \text{ or } V+$			10	μΑ

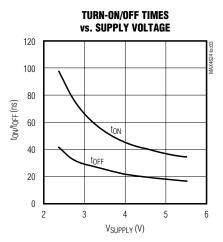
- Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- **Note 3:** SOT-packaged parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation.
- Note 4: $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 5:** Flatness is defined as the difference between the maximum and minimum values of on-resistance as measured over the specified analog signal range.
- Note 6: Guaranteed by design.
- Note 7: Off-Isolation = 20log10 [VCOM / (VNC or VNO)], VCOM = output, VNC or VNO = input to off switch.
- Note 8: Between the two switches.

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

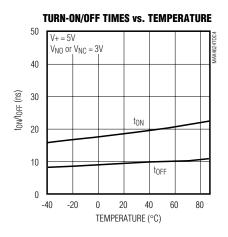


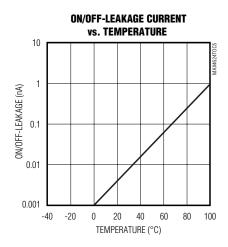


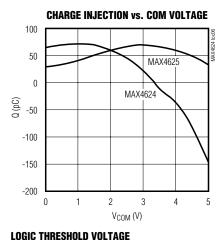


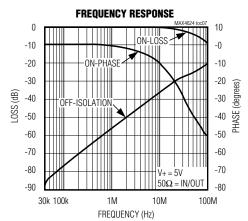
Typical Operating Characteristics (continued)

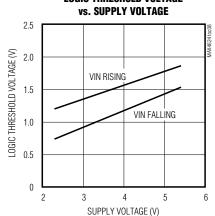
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

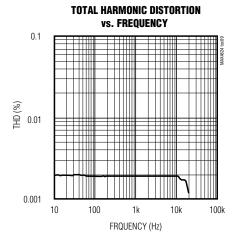


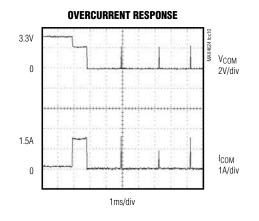












Pin Description

PIN	NAME	FUNCTION
1	IN	Digital Control Input
2	V+	Positive Supply Voltage Input
3	GND	Ground
4	NC	Analog Switch—Normally Closed
5	COM	Analog Switch—Common
6	NO	Analog Switch—Normally Open

Detailed Description

The MAX4624/MAX4625 are low-on-resistance (RoN), low-voltage, single-pole/double-throw (SPDT) analog switches that operate from a +1.8V to +5.5V supply. The MAX4624 has break-before-make switching, and the MAX4625 has make-before-break switching. These devices also have fast switching speeds ($t_{ON} = 50$ ns max, $t_{OFF} = 50$ ns max).

When powered from a +5V supply, their 1Ω max R_{ON} allows high continuous currents to be switched in a variety of applications. In an overcurrent condition, these switches provide both current-limit and thermal-shutdown protection.

Current-Limit Protection

The MAX4624/MAX4625 feature current-limit protection circuitry. When the voltage drop across the on switch reaches 0.6V typ, the internal circuitry activates. The current limit is not instantaneous, but rather integrates

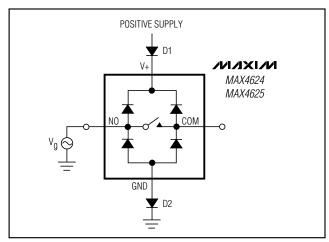


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

over time, so current limiting will not activate when the switch output charges a small $0.1\mu F$ capacitor. For sustained overload conditions, the switch turns off (opens). The switch turns on after 5ms. If the overload persists, the switch cycles off and on to produce a pulsed output. A direct short circuit will be detected immediately, and the switch will pulse on for $1\mu s$, then remain off for 5ms

Applications Information

Logic Inputs

The MAX4624/MAX4625 logic inputs can be driven up to +5.5V regardless of the supply voltage. For example, with a +3.3V supply, IN may be driven low to 0V and high to 5.5V. Driving IN Rail-to-Rail[®] minimizes power consumption.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in on-resistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO, NC, and COM pins can be used as either inputs or outputs.

Power-Supply Sequencing and Overvoltage Protection

Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices.

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited. If this sequencing is not possible, and if the analog inputs are not current limited to <20mA, add

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

a small-signal diode (D1) as shown in Figure 1. If the analog signal can dip below GND, add D2. Adding protection diodes reduces the analog range to a diode drop (about 0.7V) below V+ (for D1), and a diode drop above ground (for D2). On-resistance increases slightly at low supply voltages. Maximum supply voltage (V+) must not exceed +6V.

Adding protection diode D2 causes the logic threshold to be shifted relative to GND. TTL compatibility is not guaranteed when D2 is added.

Protection diodes D1 and D2 also protect against some overvoltage situations. With Figure 1's circuit, if the supply voltage is below the absolute maximum rating, and if a fault voltage up to the absolute maximum rating is applied to an analog signal pin, no damage will result.

Test Circuits/Timing Diagrams

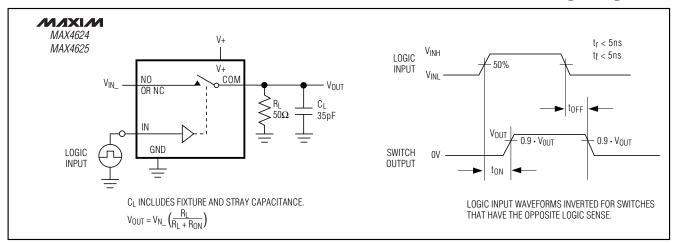


Figure 2. Switching Time

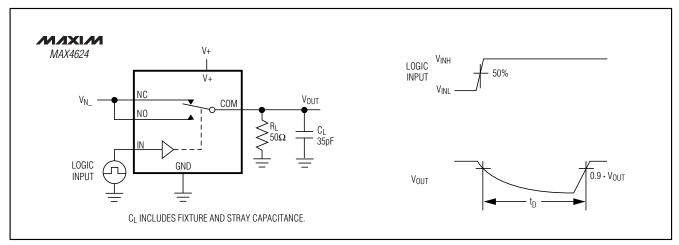


Figure 3a. Break-Before-Make Interval (MAX4624 only)

Test Circuits/Timing Diagrams (continued)

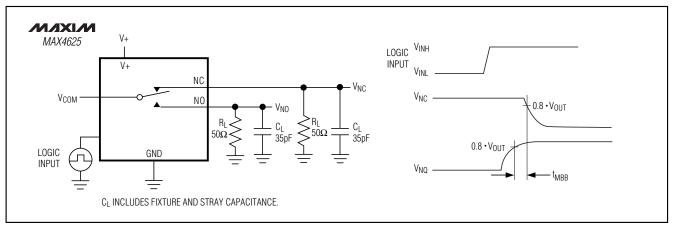


Figure 3b. Make-Before-Break Interval (MAX4625 only)

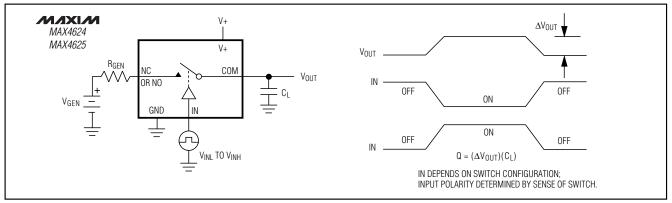


Figure 4. Charge Injection

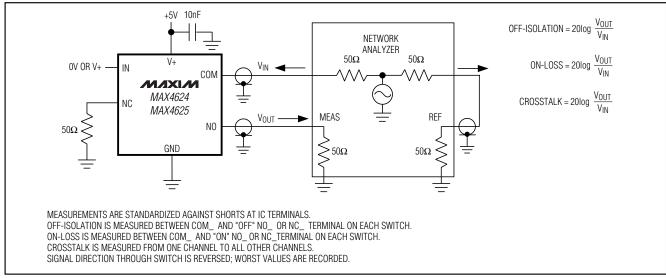


Figure 5. On-Loss, Off-Isolation, and Crosstalk

_Chip Information

TRANSISTOR COUNT: 186

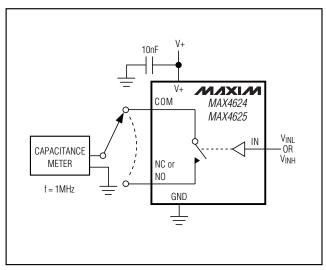
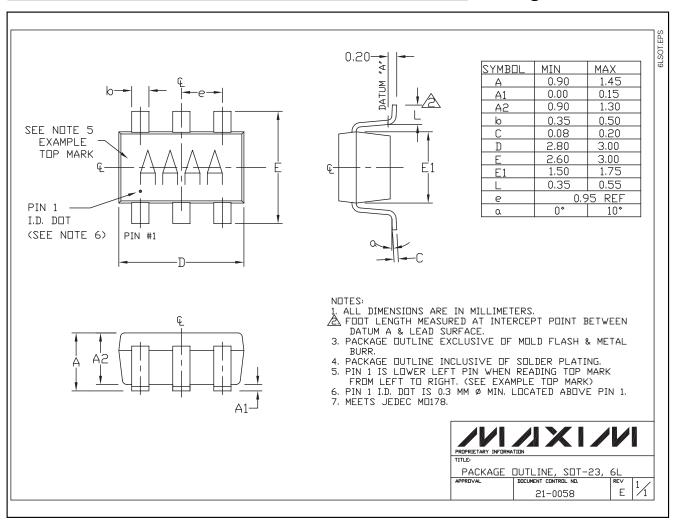
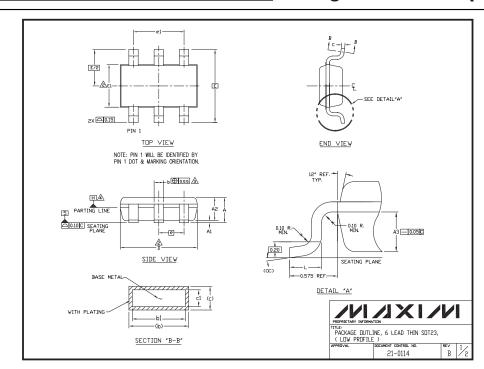


Figure 6. Channel Off/On-Capacitance

Package Information



Package Information (continued)



NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- "D" AND "E1" ARE REFERENCE DATUM AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, AND ARE MEASURED AT THE BOTTOM PARTING LINE. MOLD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15mm ON "D" AND 0.25mm ON "E" PER SIDE.
- THE LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.07mm TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.
- A DATUM PLANE "H" LOCATED AT MOLD PARTING LINE AND COINCIDENT WITH LEAD, WHERE LEAD EXITS PLASTIC BODY AT THE BOTTOM OF PARTING LINE.
- THE LEAD TIPS MUST LINE WITHIN A SPECIFIED TOLERANCE ZONE.

 THIS TOLERANCE ZONE IS DEFINED BY TWO PARALLEL LINES. ONE
 PLANE IS THE SEATING PLANE, DATUM [-C-]; AND THE OTHER
 PLANE IS AT THE SPECIFIED DISTANCE FROM [-C-] IN THE
 DIRECTION INDICATED. FORMED LEADS SHALL BE PLANAR WITH
 RESPECT TO ONE ANOTHER WITH 0.10mm AT SEATING PLANE.
- THIS PART IS COMPLIANT WITH JEDEC SPECIFICATION MO-193 EXCEPT FOR THE "e" DIMENSION WHICH IS 0.95mm INSTEAD OF 1.00mm. THIS PART IS IN FULL COMPLIANCE TO EIAJ SPECIFICATION SC-74.

SYMBOLS					
	MIN	NDM	MAX		
Α	-	-	1.10		
A1	0.05	0.075	0.10		
A2	0.85	0.88	0.90		
A3		0.50 BSC			
b	0.30	-	0.45		
b1	0.25	0.35	0.40		
С	0.15	-	0.20		
⊂1	0.12	0.127	0.15		
D	2.80	2.90	3.00		
E		2.75 BSC			
E1	1.55	1.60	1.65		
L	0.30	0.40	0.50		
e1	1.90 BSC				
е		0.95 BSC			
œ	0-	4-	8-		
aaa		0.20			



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.